High hall mobility carbonized steamed buns-based polymer memristor for neuromorphic computing and image recognition

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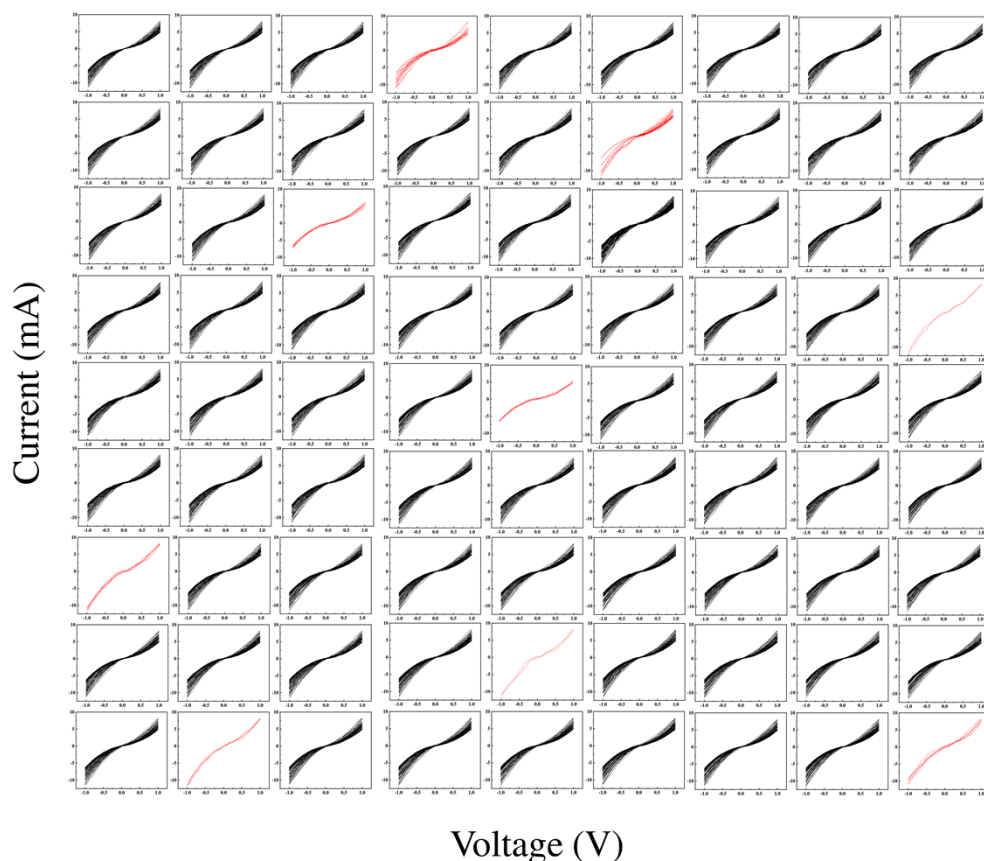
Fig. S1. The current-voltage characteristics of the Al/CSB:PVK/ITO device fabricated in a 9× 9 crossbar array. All the I-V curves were obtained by sweeping the voltage in the sequence of 0 V → −1 V → 0V → 1 V → 0 V.